

No.1405B

2SK436

unit

N-Channel Junction Silicon FET

High-Frequency, Low-Frequency General-Purpose Amp Applications

Applications

· AM tuner RF amps and low-noise amps.

Features

- \cdot Large | $\mathbf{y}_{\mathbf{fs}}$ | .
- · Ultralow noise figure.
- · Small Crss.
- · Ultrasmall-sized package permitting 2SK436-applied sets to be made small and slim.

Absolute Maximum Ratings at Ta = 25°C

Drain-to-Source Voltage	$ m V_{DSS}$	15	V
Gate-to-Drain Voltage	V_{GDS}	-15	v
Gate Current	$\mathbf{I}_{\mathbf{G}}$	10	mA
Drain Current	$I_{\mathbf{D}}$	20	mA
Allowable Power Dissipation	$P_{\mathbf{D}}$	150	mW
Junction Temperature	Tj	125	°C
Storage Temperature	Tstg	-55 to +125	°C

Electrical Characteristics at Ta = 25°C

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	G-D Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10 \mu A, V_{DS} = 0$	-15			V
	Gate Cutoff Current	I_{GSS}	$V_{GS} = -10V, V_{DS} = 0$			-1.0	nΑ
	Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 5V, I_D = 100 \mu A$		-0.5	-1.5	V
	Drain Current	I_{DSS}	$V_{DS}=5V,V_{GS}=0$	1.2 %	(12.0 %	$\mathbf{m}\mathbf{A}$
	Forward Transfer Admittance	У _{fs}	$V_{DS} = 5V, V_{GS} = 0, f = 1kHz$	8.0	17		mS
	Input Capacitance	Ciss	$V_{DS} = 5V, V_{GS} = 0, f = 1MHz$		7.0		\mathbf{pF}
	Reverse Transfer Capacitance	Crss	$V_{DS}=5V, V_{GS}=0, f=1MHz$		2.0		\mathbf{pF}
	Noise Figure	NF	$V_{DS} = 5V, I_D = 1mA, Rg = 1k\Omega$		1.5		dΒ
			f=1kHz				

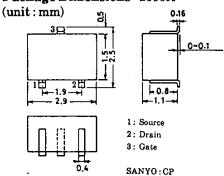
X: The 2SK436 is classified by I_{DSS} as follows: (unit: mA)

1.2 17	2.1	1.7	18	3.0	2.5	19	4.2
3.5 20	6.0	5.0	21	8.5	7.3	22	12.0

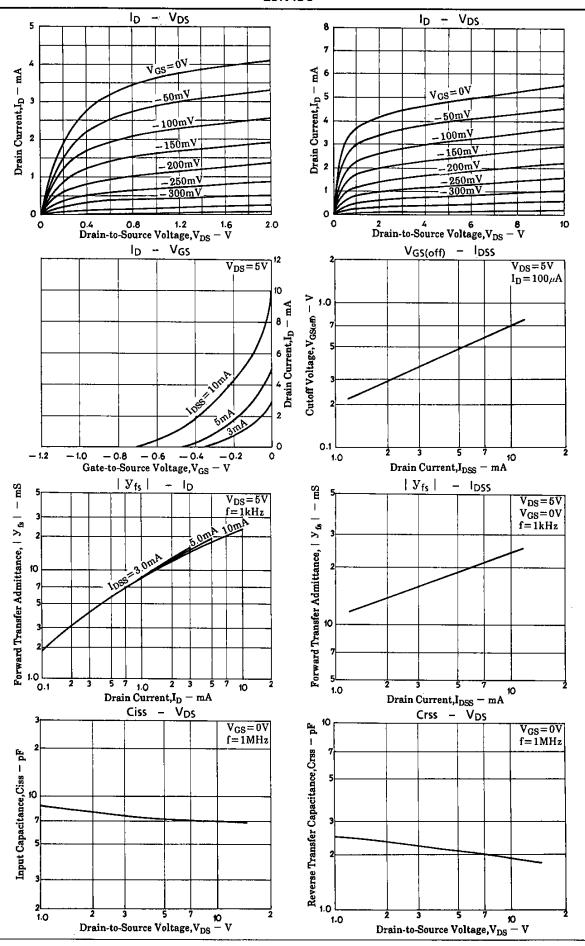
Note) Marking: A

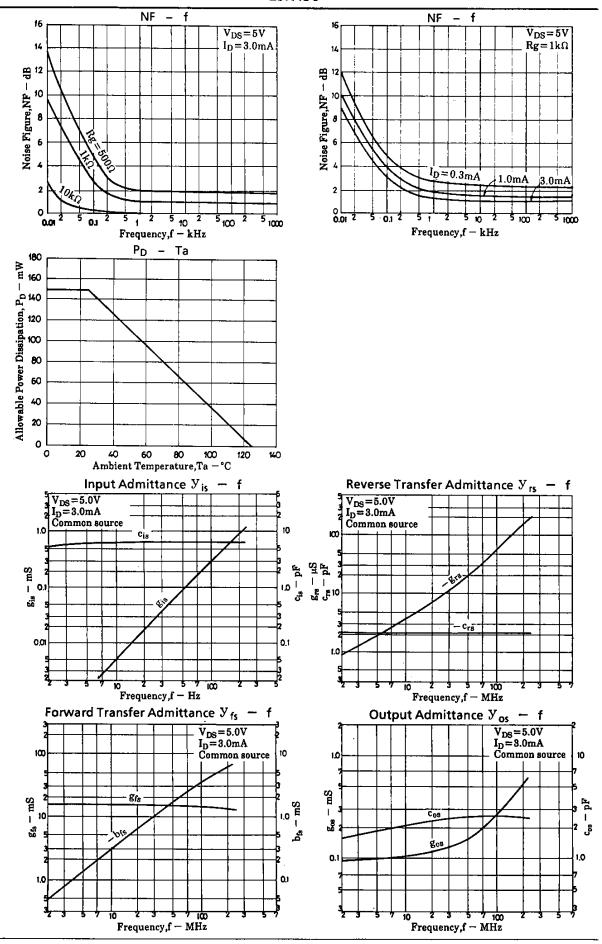
I_{DSS} rank: 17, 18, 19, 20, 21, 22

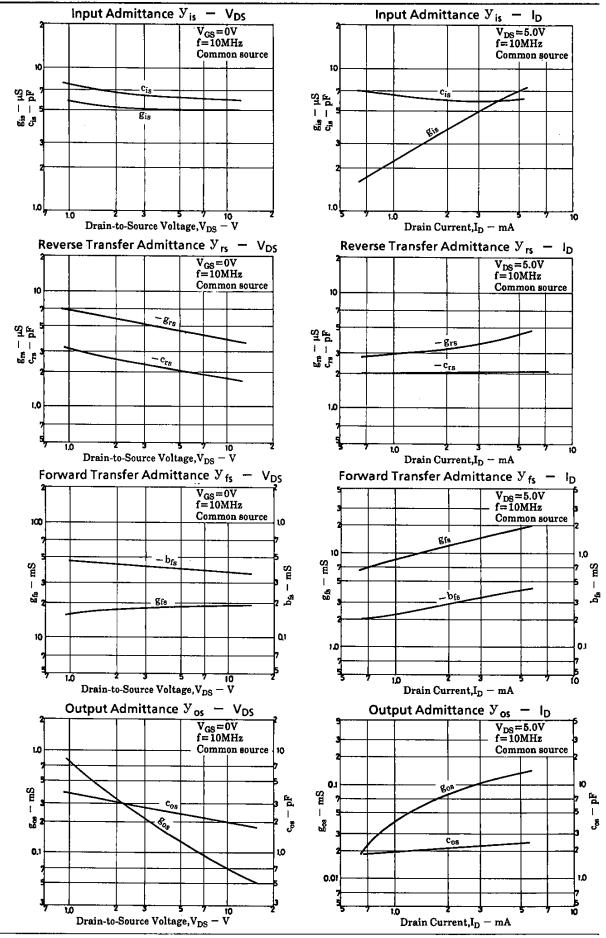
Package Dimensions 2050A

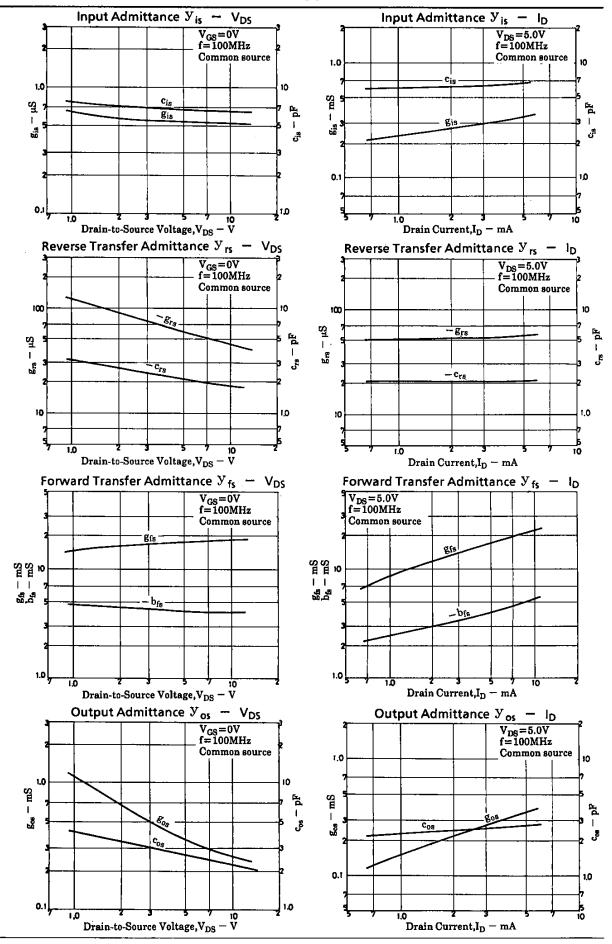


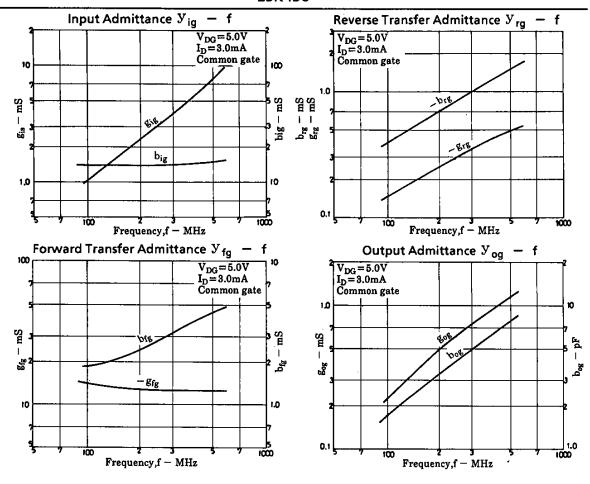
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